



SBRT2M10LP

2A Trench SBR TRENCH SUPER BARRIER RECTIFIER

Product Summary

V _{RRM} (V)	I _O (A)	V _F (MAX) (V) @ +25°C	I _{R(MAX)} (mA) @ +25°C	
10	2	0.4	0.15	

Features and Benefits

- Patented Trench SBR Technology Provides Superior Avalanche Capability Versus Schottky Diodes, Ensuring More Rugged and Reliable End Applications
- Reduced Ultra-low Forward Voltage Drop (V_F); Better Efficiency and Cooler Operation
- Reduced High Temperature Reverse Leakage; Increased Reliability Against Thermal Runaway Failure in High Temperature Operation
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Description and Applications

The SBRT2M10LP provides very low V_F and excellent reverse leakage stability at high temperatures. It is ideal for use as a rectifier, freewheel diode or blocking diode in applications such as:

- Solar Panels
- Portable Electronics

Mechanical Data

- Case: X1-DFN1411-3
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Polarity: See Below
- Weight: 2.35 mg (Approximate)

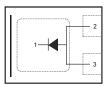
X1-DFN1411-3







Bottom View



Top View Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
SBRT2M10LP-7	X1-DFN1411-3	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

X1-DFN1411-3

D1 ≻

D1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: B = 2014) M = Month (ex: 6 = June)

Date Code Key

Year	2014	20)15	2016	2017	20	18	2019	2020	20	21	2022
Code	В		С	D	Е		=	G	Н		I	J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

T_A = 175°C



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	10	V
Average Rectified Output Current	lo	2	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	25	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Case (Note 5)	R _{0JC}	25	°C/W
Typical Thermal Resistance Junction to Ambient (Note 5)	$R_{\theta JA}$	100	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

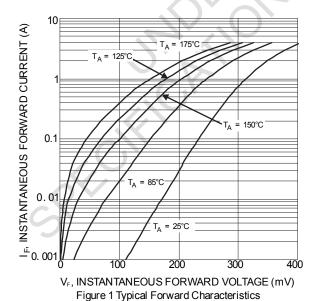
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop (Note 6)	V _F	\times	0.348	0.400	V	I _F = 2A, T _J = +25°C
Leakage Current (Note 6)	I _R) = 6	62 10.8	150 —	' .	$V_R = 10V, T_J = +25^{\circ}C$ $V_R = 10V, T_J = +125^{\circ}C$

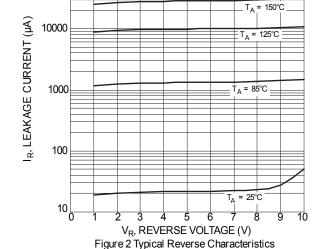
Notes:

5. Device mounted on FR4 PCB pad layout 1inch 2oz copper pad as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com.

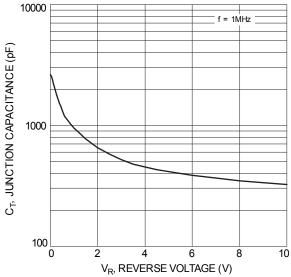
100000

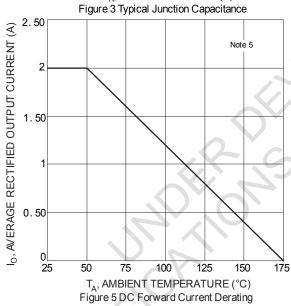
6. Short duration pulse test used to minimize self-heating effect.

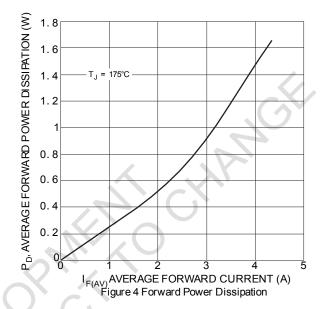








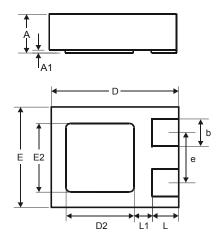






Package Outline Dimensions

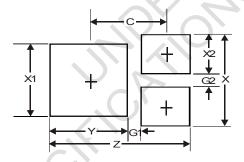
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X1-DFN1411-3							
Dim	Min	Max	Тур				
Α	0.47	0.53	0.50				
A1	0.00	0.05	0.02				
b	0.25	0.35	0.30				
D	1.35	1.475	1.40				
D2	0.65	0.85	0.75				
E	1.05	1.175	1.10				
E2	0.65	0.85	0.75				
е	_	_	0.55				
L	0.225	0.325	0.275				
L1		_	0.20				
All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	1.38
G1	0.15
G2	0.15
Х	0.95
X1	0.75
X2	0.40
Υ	0.75
С	0.76



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